

QPA4563A

DC to 3500MHz, CASCADABLE SiGe HBT MMIC AMPLIFIER

The QPA4563A is a high performance SiGe HBT MMIC amplifier. A Darlington configuration provides high F_T and excellent thermal performance. The heterojunction increases breakdown voltage and minimizes leakage current between junctions. Cancellation of emitter junction non-linearities results in higher suppression of intermodulation products. Only two DC-blocking capacitors, a bias resistor, and an optional RF choke are required for operation.

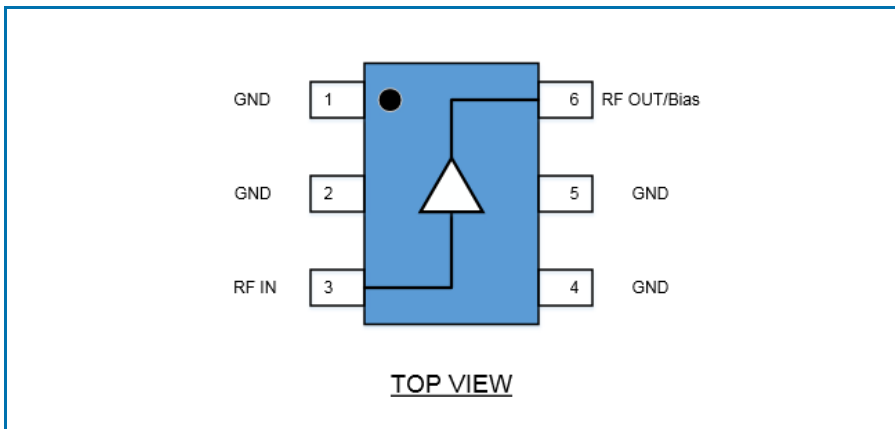


SOT-363 Package

Features

- DC to 3500MHz Operation
- Cascadable 50Ω
- High Gain: 20.4 dB Typical at 1950 MHz
- Operates From Single DC Supply
- Low Thermal Resistance Package

Functional Block Diagram



Applications

- Power Amplifier Driver Amplifier
- Cellular, PCS, GSM, UMTS
- IF/RF Buffer Amplifier
- Wireless Data, Satellite

Ordering Information

QPA4563ASQ	Sample Bag with 25 pieces
QPA4563ASR	7" Reel with 100 pieces
QPA4563ATR7	7" Reel with 3000 pieces
QPA4563APCK401	850MHz, +8V Operation PCBA with 5-piece Sample Bag

QPA4563A

Absolute Maximum Ratings

Parameter	Rating	Units
Device Voltage(V _D)	+5.0	V
Device Current (I _D)	90	mA
RF Input Power ^{Note 1}	+18	dBm
Storage Temperature	-55 to +150	°C
ESD Rating (HBM)	TBD	-
Moisture Sensitivity Level	MSL1	-

Notes:

1. Load Condition 1: Z_L = 50 Ω
2. Operation of this device beyond any one of these limits may cause permanent damage. For reliable continuous operation, the device voltage and current must not exceed the maximum operating values specified in this table.
3. Bias Conditions should also satisfy the following expression: I_DV_D < (T_J - T_L) / R_{TH}, and T_L = T_{LEAD}.



Caution! ESD sensitive device.



RFMD Green: RoHS status based on EU Directive 2011/65/EU (at time of this document revision), halogen free per IEC 61249-2-21, < 1000 ppm each of antimony trioxide in polymeric materials and red phosphorus as a flame retardant, and <2% antimony in solder.

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implied.

Recommended Operating Conditions

Parameter	Rating			Units
	Min	Typ	Max	
Operating Temperature Range	-40		+105	°C
Junction Temperature (T _J)			+125	°C
Device Operating Voltage		+3.6		V

Electrical Specifications – General

Parameter	Specification			Units	Conditions
	Min	Typ	Max		
Small Signal Gain, S ₂₁		23.5		dB	850MHz
		20.4		dB	1950MHz
		19.2		dB	2400MHz
Output Power at 1 dB Compression		+16.0		dBm	850MHz
		+16.2		dBm	1950MHz
		+15.8		dBm	2400MHz
Output Third Order Intercept Point		+30.0		dBm	850MHz
		+29.4		dBm	1950MHz
		+28.9		dBm	2400MHz
Input Return Loss, S ₁₁		28.7		dB	850MHz
		17.1		dB	1950MHz
		16.9		dB	2400MHz
Output Return Loss, S ₂₂		25.0		dB	850MHz
		14.9		dB	1950MHz
		14.2		dB	2400MHz

Test Conditions unless otherwise specified: +V_D = +3.6 V, V_S = +8 V, I_D = 45 mA Typ., OIP3 Tone Spacing=1 MHz, P_{OUT} per tone = -10 dBm, R_{BIAS} = 100Ω, T_L = +25°C, Z_S = Z_L = 50 Ω

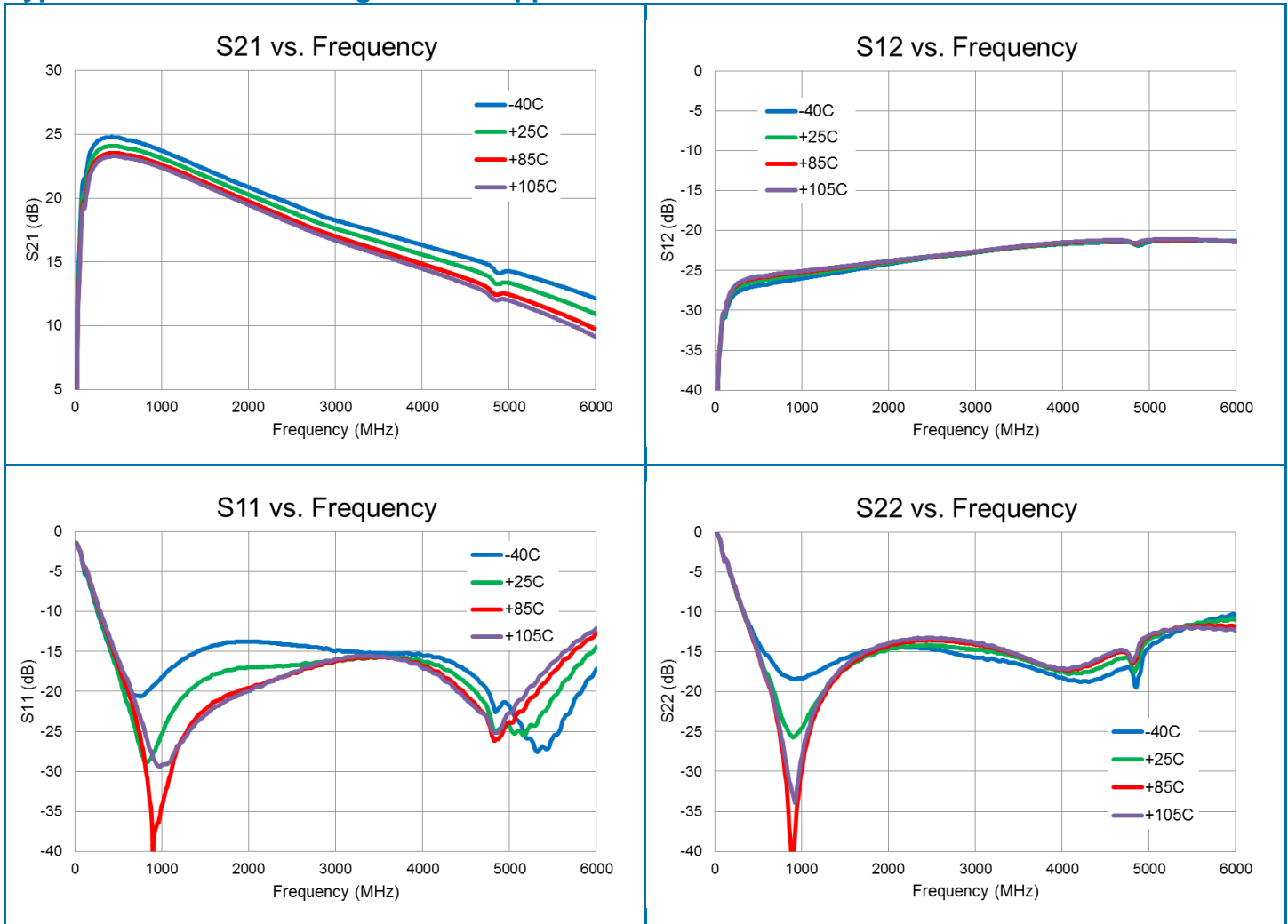
QPA4563A

Electrical Specifications – General (Continued)

Parameter	Specification			Units	Conditions
	Min	Typ	Max		
Reverse Isolation, S12		25.8		dB	850MHz
		24.1		dB	1950MHz
		23.5		dB	2400MHz
Noise Figure		2.3		dB	850MHz
		2.5		dB	1950MHz
		2.8		dB	2400MHz
Thermal Resistance		118		°C/W	
Device Operating Current		45		mA	

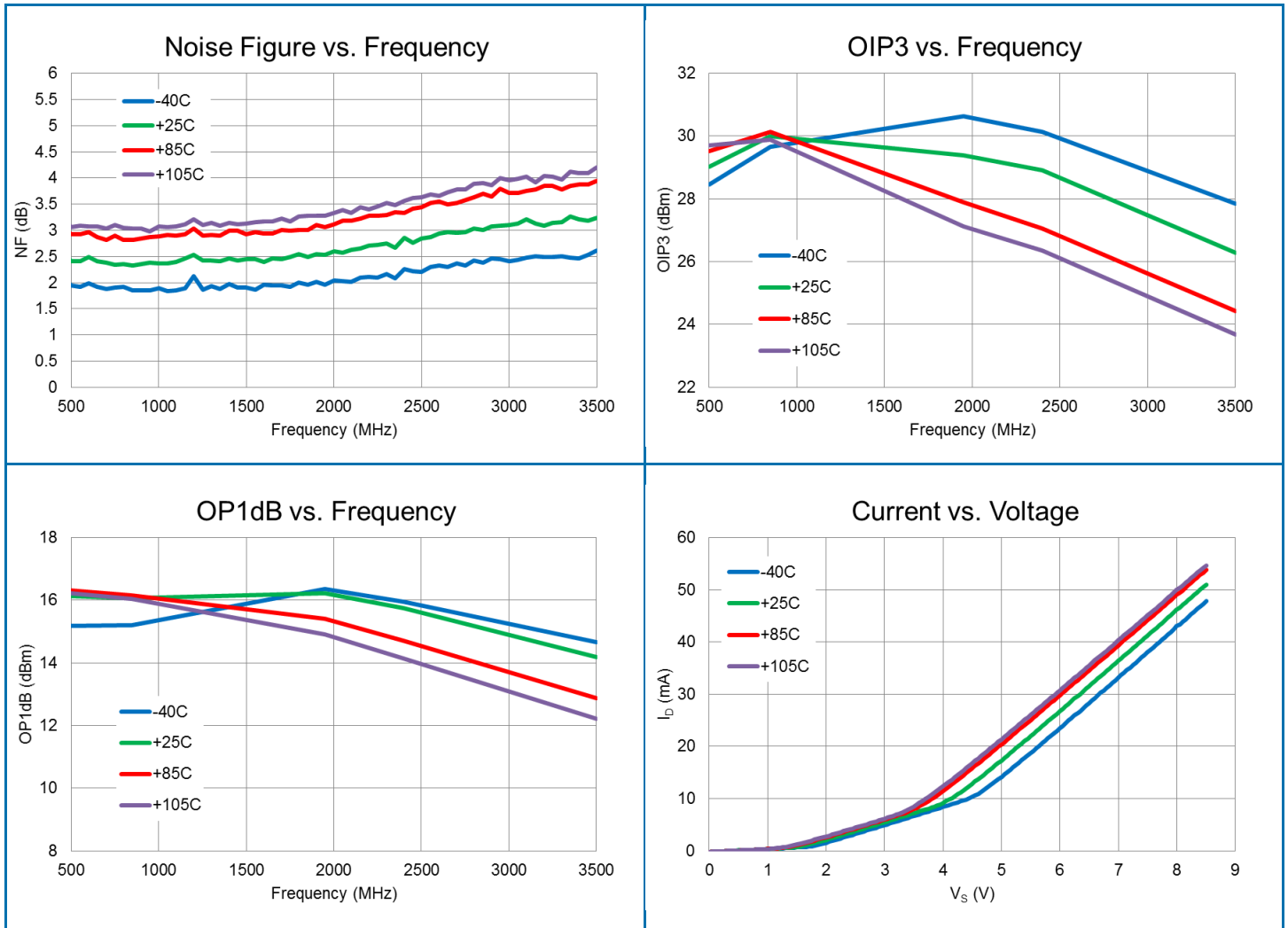
Test Conditions unless otherwise specified: $+V_D = +3.6\text{ V}$, $V_S = +8\text{ V}$, $I_D = 45\text{ mA Typ.}$, OIP3 Tone Spacing=1 MHz, P_{OUT} per tone = -10 dBm, $R_{BIAS} = 100\Omega$, $T_L = +25^\circ\text{C}$, $Z_S = Z_L = 50\Omega$

Typical Performance Using 850MHz Application Circuit



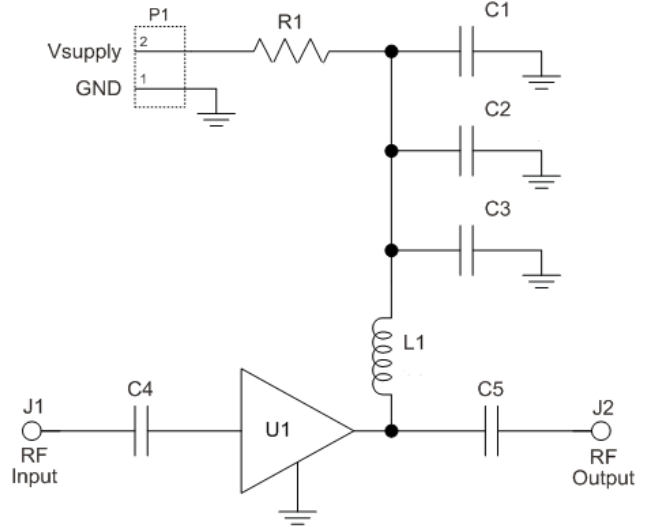
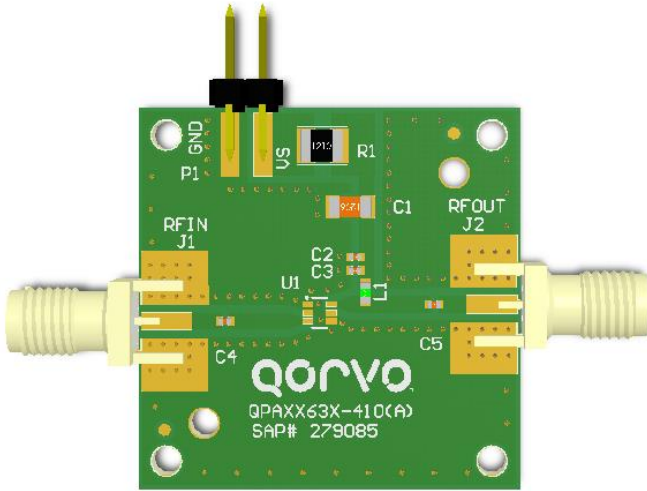
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Typical Performance Using 850MHz Application Circuit



QPA4563A

Evaluation Board and Schematic



Evaluation Board Bill of Materials For 850MHz Application Circuit

Description	Reference Designator	Manufacturer	Manufacturer's P/N
Gain Block	U1	QORVO	QPA4563A
PCB	NA	Viasystems Technologies Corp	QPAXX63X-410(A)
CAP, 1uF, 10%, 25V, X7R, 1206	C1	Murata Electronics	GRM31MR71E105KA01L
CAP, 1000pF, 10%, 50V, X7R, 0402	C2	Murata Electronics	GRM155R71H102KA01D
CAP, 68pF, 5%, 50V, C0G, 0402	C3	Murata Electronics	GRM1555C1H680JA01D
CAP, 100pF, 5%, 50V, C0G, 0402	C4, C5	Murata Electronics	GRM1555C1H101JA01D
RES, 100 OHM, 5%, 1/2W, 1210	R1	Panasonic Industrial Devices	ERJ-14YJ101U
IND, 33nH, 5%, M/L, 0603	L1	Murata Electronics	LL1608-FSL33NJ
CONN, SMA, EL, FLT, 0.068" SPE-000318	J1, J2	Amphenol RF Asia Corp	901-10426
CONN, HDR, ST, 1x2, 0.100", HI-TEMP, T/H	P1	Samtec Inc.	HTSW-102-07-G-S

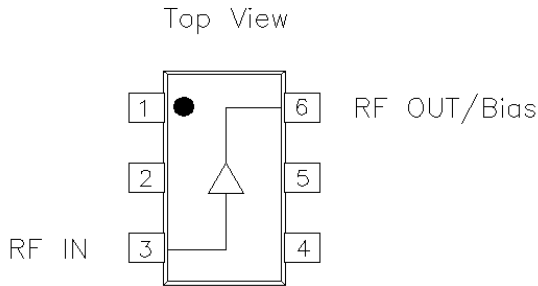
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Component Values For Specific Frequency and Voltage in Application Circuit

Reference Designator	Frequency (MHz)				
	500	850	1950	2400	3500
C ₄ , C ₅	220pF	100pF	68pF	56pF	39pF
C ₃	100pF	68pF	22pF	22pF	15pF
L ₁	68nH	33nH	22nH	18nH	15nH
Required Bias Resistance for I_D = 45mA Bias Resistance = R_{BIAS} + R_{LDC} = (V_S - V_D) / I_D					
Supply Voltage (V _S)	+6 V	+8 V	+10 V	+12 V	
Bias Resistance (R ₁ = R _{Bias})	51 Ω	100 Ω	150 Ω	180 Ω	

*Note: Bias resistor improves current stability over temperature

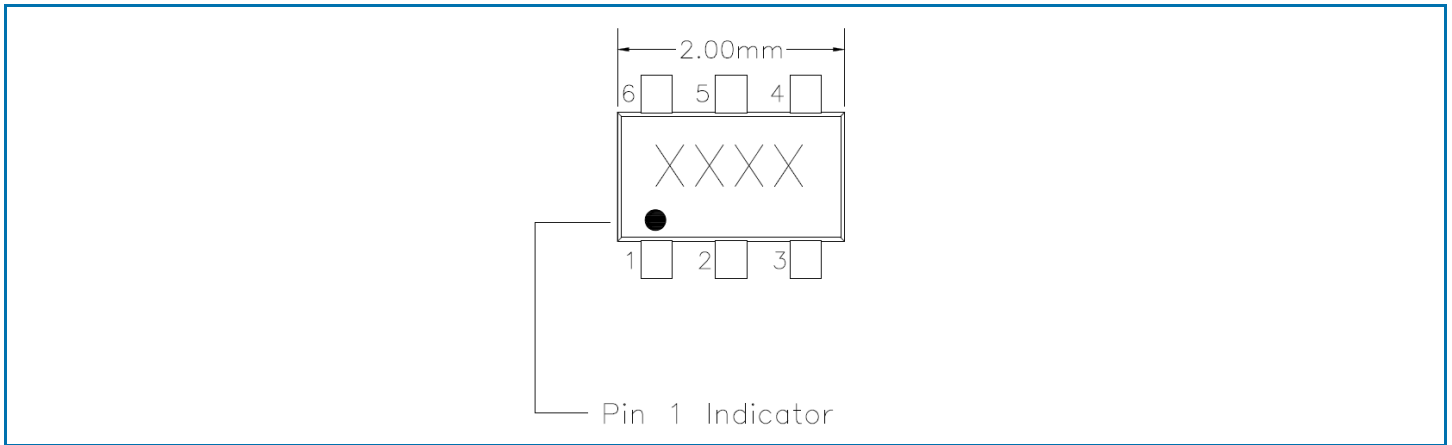
Pin Configuration and Description



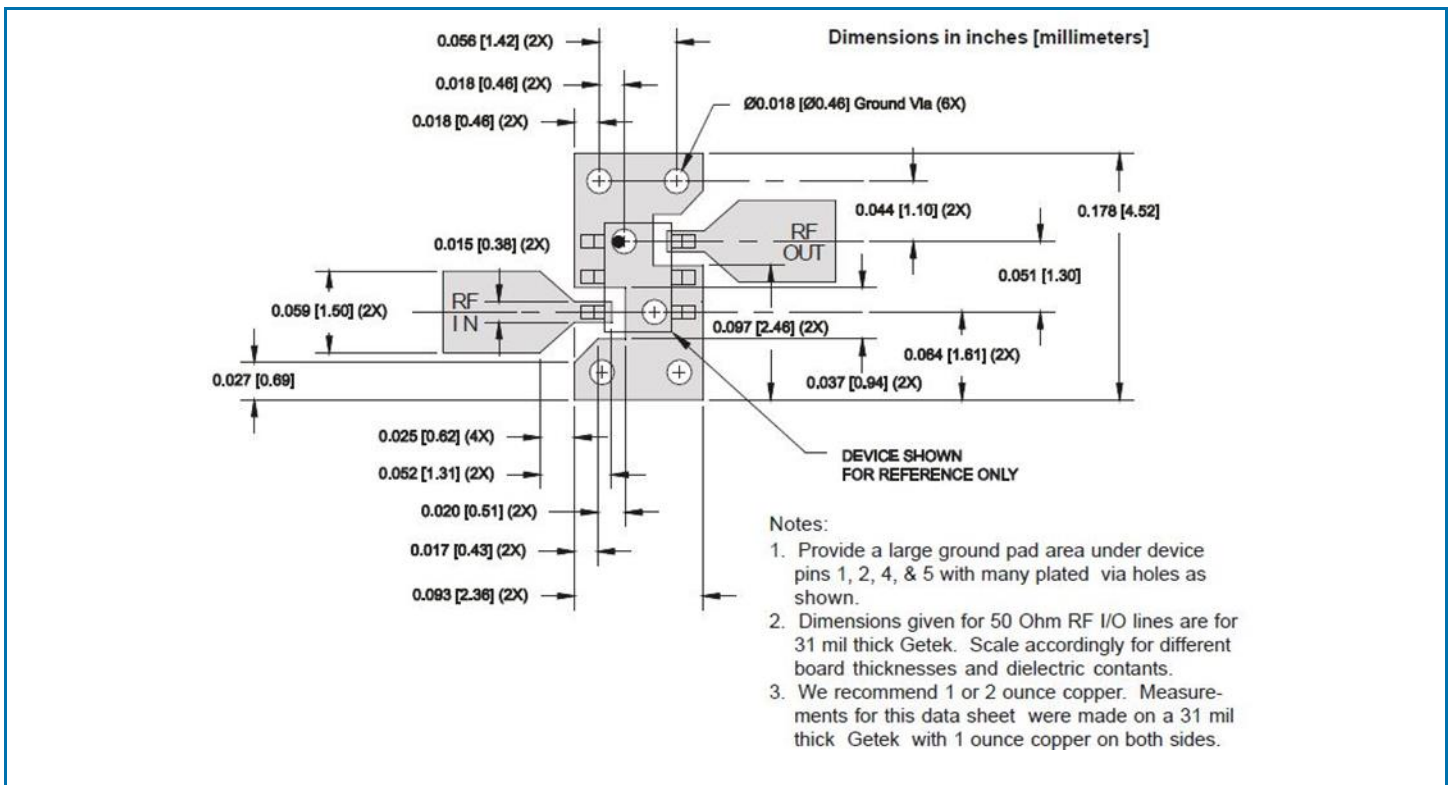
Pin	Label	Description
3	RF IN	RF Input pin. This pin requires the use of an external DC blocking capacitor as shown in the application schematic.
1, 2, 4, 5	GND	Connect to ground per application circuit drawing. For best performance, vias should be used as shown in the recommended pad layout.
6	RF OUT/BIAS	RF Output and Bias pin. Bias will be supplied to this pin through an external RF choke. A DC blocking capacitor is necessary on the RF output as shown in the application circuit.

QPA4563A

Package Marking



Suggested Pad Layout (Dimensions in inches [millimeters])



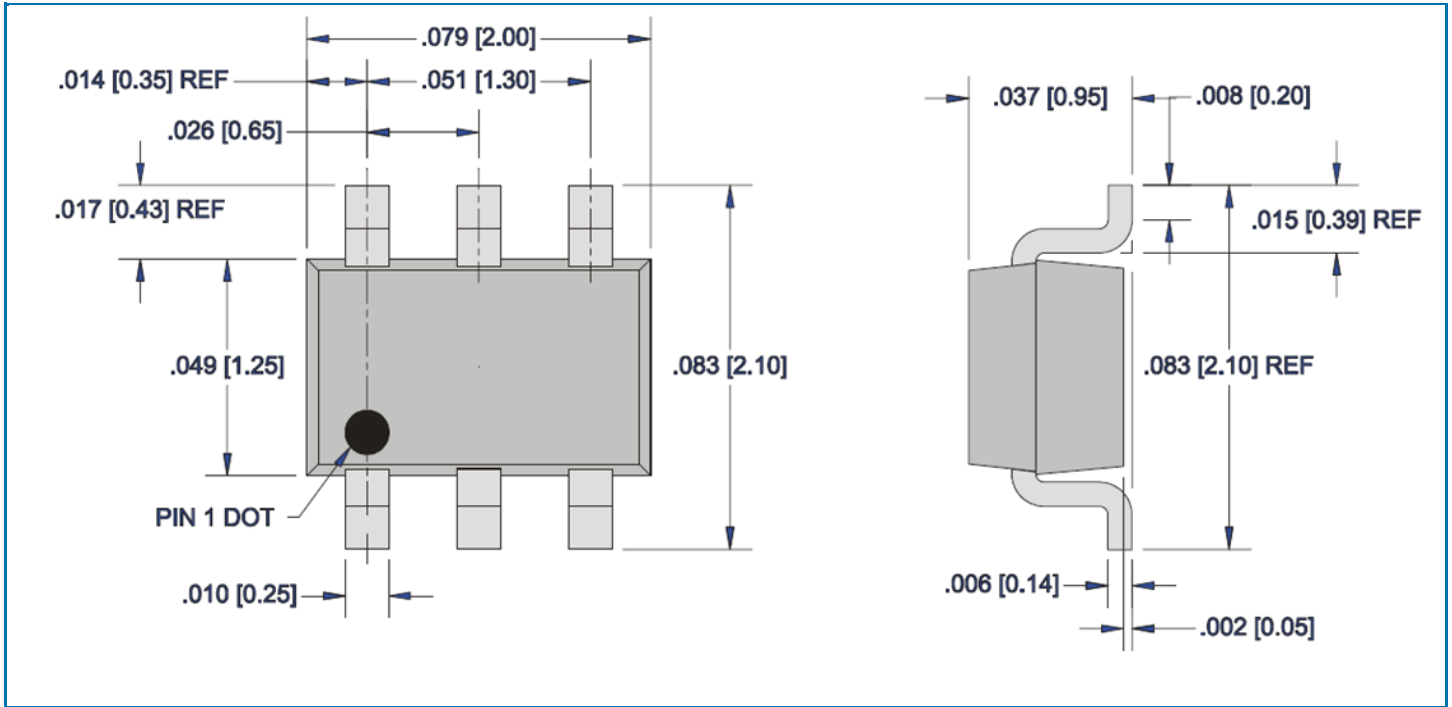
Preliminary



RFMD + TriQuint = Qorvo

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Package Outline (Dimensions in inches [millimeters])



Contact Information

For the latest specifications, additional product information, worldwide sales and distribution locations:

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Tel: 1-844-890-8163

For information about the merger of RFMD and TriQuint as Qorvo:

Web: www.qorvo.com

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